

QUICKSWITCH[®] PRODUCTS HIGH-PERFORMANCE CMOS TWO CHANNEL 5PST SWITCH

FEATURES:

- Low ON resistance: rbs(on) = 5Ω
- Wide bandwidth: 1.8GHz (-3dB point)
- Crosstalk: 100dB at 50KHz, -70dB at 5MHz, -50dB at 30MHz
- Off-isolation: -70dB at 50KHz, -45dB at 5MHz, -40dB at 30MHz
- Single 5V supply
- Bidirectional
- TTL-compatible control inputs
- Ultra-low quiescent current: 3µA
- · Switch turn on time of 6.5ns
- Available in QSOP package

APPLICATIONS:

- · High-speed video signal switching/routing
- HDTV-quality video signal routing
- Audio signal switching/routing
- Data acquisition
- ATE systems
- Telecomm routing
- Token Ring transceivers
- High-speed networking

FUNCTIONAL BLOCK DIAGRAM

DESCRIPTION:

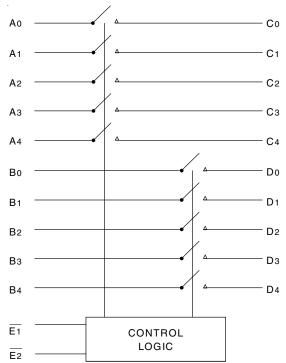
The QS4A110 is a high-performance CMOS two-channel 5PST switch with 3-state outputs. The low ON resistance of the QS4A110 allows inputs to be connected to outputs with low insertion loss and high bandwidth.

The QS4A110, with 1.8GHz bandwidth, is ideal for high-performance video signal switching, audio signal switching, and telecomm routing applications. Low power dissipation makes this device ideal for battery operated and remote instrumentation applications.

The QS4A110 is offered in the QSOP package which has several advantages over conventional packages such as PDIP and SOIC, including:

- Reduced signal delays due to denser component packaging on circuit boards
- · Reduced system noise due to less pin inductance

The QS4A110 is characterized for operation at -40°C to +85°C.



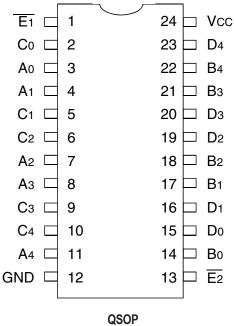
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INDUSTRIAL TEMPERATURE RANGE

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APRIL 2014

PIN CONFIGURATION



TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit	
VTERM ⁽²⁾	Supply Voltage to Ground	–0.5 to +7	V	
VTERM ⁽³⁾	DC Switch Voltage Vs	0 to +7	V	
—	Analog Input Voltage	0 to +7	V	
VTERM ⁽³⁾	DC Input Voltage VIN	0 to +7	V	
VAC	AC Input Voltage (pulse width ≤20ns)	_3	V	
Ιουτ	DC Output Current	120	mA	
Рмах	Maximum Power Dissipation	0.7	W	
Tstg	STG Storage Temperature		°C	

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc .

PIN DESCRIPTION

Pin Names	I/O	Description
Ax, Bx	I/O	Ports A, B
Cx, Dx	I/O	Ports C, D
Ē1 -Ē2	Ι	Enable

FUNCTION TABLE(1)

Ē1	Ē2	Ax, Cx I/Os	Bx, Dx I/Os
Н	Н	Disconnected	Disconnected
L	Н	Ax = Cx	Disconnected
Н	L	Disconnected	Bx = Dx
L	L	Ax = Cx	Bx = Dx

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Industrial: TA = -40° C to $+85^{\circ}$ C. Vcc = 5V ± 5%

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
Analog S	witch	-	I	-		
Vin	Analog Signal Range ⁽²⁾		-0.5	1	Vcc - 1	V
rds(on)	Drain-source ON resistance ^(2,3)	Vcc = Min., VIN = 0V, ION = 30mA	_	5	7	Ω
		Vcc = Min., VIN = 2.4V, ION = 15mA	—	13	17	
IC(OFF)	Channel Off Leakage Current	Ax, Bx = Vcc or 0V; Cx, Dx = 0V or Vcc; \overline{E} = Vcc	—	1	-	nA
IC(ON)	Channel On Leakage Current	Ax = Bx = 0V	-	1	_	nA
		(each channel is turned on sequentially)				
Digital Co	ontrol					
Vih	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	-	_	V
VIL	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	—	-	0.8	V
Dynamic	Characteristics					
ton(Ē)	Enable Turn-On Time	RL = 1KΩ, CL = 100pF	0.5	_	6	ns
	Ē to Ax, Bx, Cx, or Dx	(See Switching Time)				
toff(Ē)	Enable Turn-Off Time	RL = 1KΩ, CL = 100pF	0.5	-	6.5	ns
	Ē to Ax, Bx, Cx, or Dx	(See Switching Time)				1
t PD	Group Delay ^(2,4a)	RL = 1KΩ, CL = 100pF	—	_	250	ps
f3dB	-3dB Bandwidth	VIN = 0 to 1V, 1Vp-p, RL = 75Ω	-	1.8	_	GH
	Off-isolation	VIN = 0 to 1V, 1Vp-p, RL = 75Ω, f = 5.5MHz	_	-45	_	dB
Xtalk	Crosstalk	VIN = 0 to 1V, 1Vp-p, RL = 75Ω, f = 5.5MHz	_	-70	_	dB
C(OFF)	Switch Off Capacitance	\overline{E} = Vcc, VIN = VOUT = 0V	_	5	_	pF
C(ON)	Switch On Capacitance	Ē = 0V, VIN = VOUT = 0V	_	10	_	pF
QCI	Charge Injection	·		1.5		рC

NOTES:

1. Typical values are at Vcc = 5.0V, TA = 25°C.

2. Max value is guaranteed but not production tested.

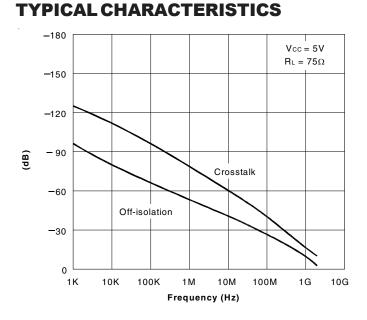
3. Measured by voltage drop between A and C pins or B and D pins at indicated current through the switch. ON resistance is determined by the lower of the voltages on the two (A, C, or B, D) pins.

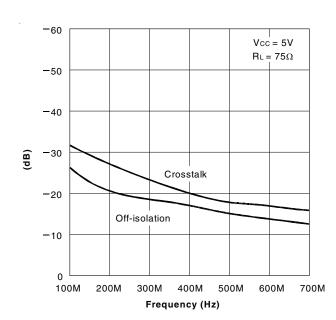
4. The bus switch contributes no group delay other than the RC delay of the ON resistance of the switch and load capacitance. Group delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

POWER SUPPLY CHARACTERISTICS

Symbo	Parameter	Test Conditions	Max.	Unit
Icc	Supply Current	Vcc = Max., Vin = GND or Vcc	3	μΑ

DTQS4A110



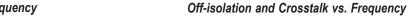


Off-isolation and Crosstalk vs. Frequency



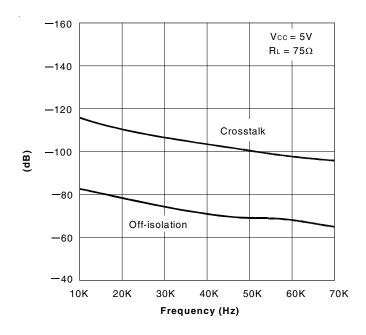
1. Crosstalk = 20 log $|V_0/V_s|$

2. Off-isolation = 20 log |Vo/Vs|





1. Crosstalk = 20 log |Vo/Vs| 2. Off-isolation = 20 log |Vo/Vs|

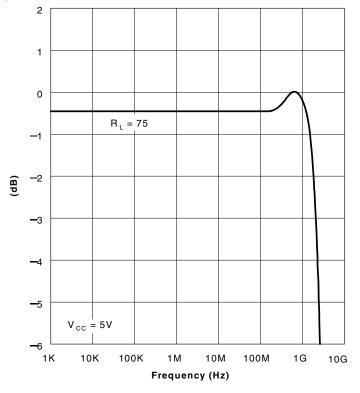


Off-isolation and Crosstalk vs. Frequency

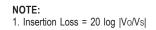
NOTES:

1. Crosstalk = 20 log $|V_0/V_s|$ 2. Off inclution = 20 log $|V_0/V_s|$

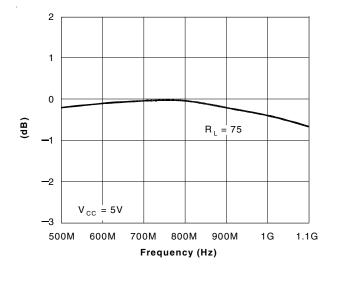
2. Off-isolation = 20 log |Vo/Vs|



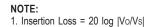
Insertion Loss vs. Frequency



TYPICAL CHARACTERISTICS (CONTINUED)



Insertion Loss vs. Frequency





3.0

2.5

On-Resistance vs. VIN

1.5

VIN (Volts)

2.0

1.0

Vcc = 4.75V

18

16

14

12

10

8

6

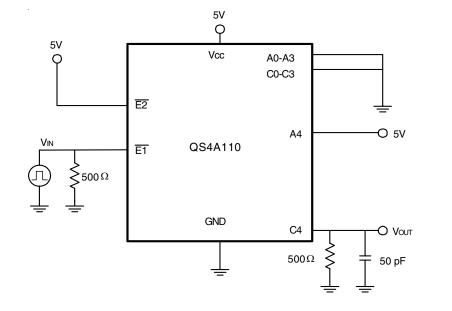
4

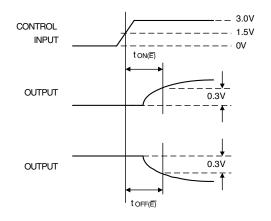
0.0

0.5

r DS(On) - Drain Source On-resistance(Ω)

TEST CIRCUITS





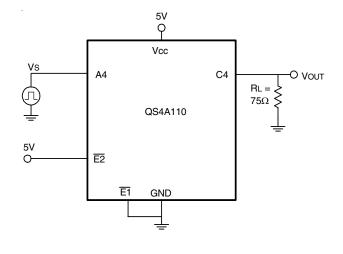
Switching Time

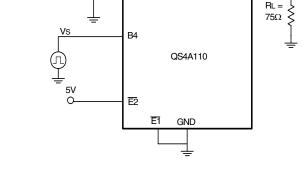
C1

RL =

-O Vout

TEST CIRCUITS (CONTINUED)





A1

5V Q

Vcc

Crosstalk

Insertion Loss



- Insertion Loss = 20 log |Vo/Vs|
 All unused pins are grounded.

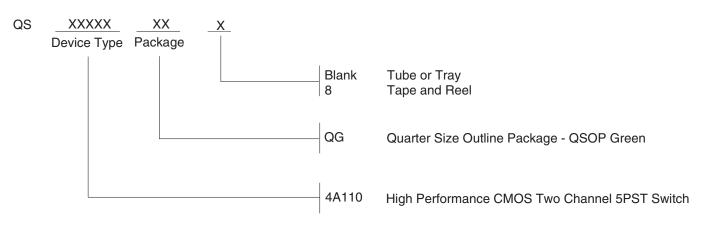
5V 9 Vcc Vs C1 O VOUT A1 RL = Ş 75Ω QS4A110 5V Q Ē1 Ē2 GND

Off-Isolation

NOTE: 1. Off-isolation = 20 log |Vo/Vs|

NOTES: 1. Crosstalk = 20 log |Vo/Vs| 2. All unused pins are grounded.

ORDERING INFORMATION



DATASHEET DOCUMENT HISTORY

04/13/2014 Pg. 7 Updated the Ordering Information by removing non green package version and Adding Tape and Reel information.

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